

PH920DBR 920nm Series

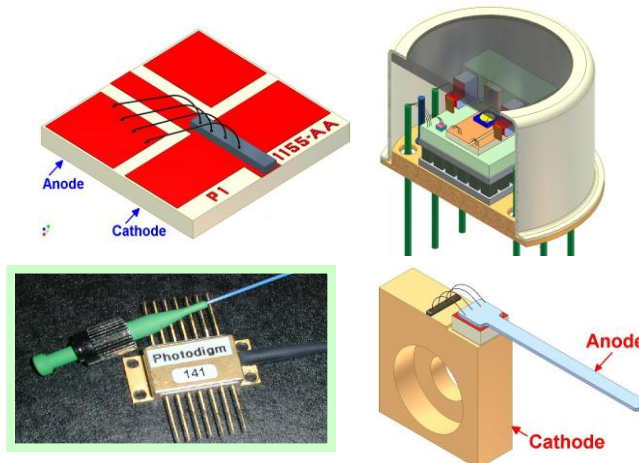
High-Power Single-Frequency Laser Diode

Technology

- DBR Single-Frequency Laser Chip
- InGaAs QW Active Layer
- Epi designed for high reliability

Features

- Available in several package styles
- Pulsed operation for spectral stability at short pulse lengths
- High power for CW applications
- High Slope Efficiency



Description

The PH920DBR Series of high-power edge-emitting lasers are based on Photodigm's advanced single-frequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam. Facets are passivated for high-power reliability. Applications include spectroscopy, difference frequency generation, and low power DPSS replacement.

Absolute Maximum Ratings

Parameter	Symbol	Unit	Min	Max
Storage Temperature	T_{STG}	°C	0	80
Operating Temperature	T_{OP}	°C	5.0	70
CW Laser Forward Current, $T=T_{op}$	I_F	mA	-	150**
Pulsed Laser Forward Current, $T=25^{\circ}C$, PW=300 ns, DC=10%	I_F	A	-	0.5
Laser Reverse Voltage	V_R	V	-	2.0
Photodiode Forward Current 1/ 2/	I_P	mA	-	5.0
Photodiode Reverse Voltage 1/ 2/	V_R	V	-	20.0
Photodiode Dark Current, $V_R=10V$, LD $I_F=0$, 1/ 2/	I_D	nA	-	50
TEC Current 1/ 2/	I_{TEC}	A	-2.5	2.5
TEC Voltage 1/ 2/	V_{TEC}	V	-6.0	6.0
Thermistor Current 1/ 2/	I_{THRM}	mA	-	1.0
Thermistor Voltage 1/ 2/	V_{THRM}	V	-	10
ESD (HBM)	-	V	-	500
External Back Reflection	-	dB	-	-14
Lead Soldering Temperature, 10 sec. Max., 1/ 2/	-	°C	-	260
Fiber Pull Force 1/	-	N	-	5.0
Fiber Bend Radius 1/	-	mm	-	35

1/ Butterfly package 2/ TO-8 package **Do not exceed drive current or operating power of supplied LIV**

CW Characteristics at T_C = 25°C unless otherwise specified

Parameter	Symbol	Unit	Min	Typ	Max
Center Wavelength	λ_c	nm	918	920	922
Optical Output Power @ LIV current	P _o	mW	See Power Options Call-out		
Slope Efficiency, 1/	η_d	W/A	0.3	0.36	
Slope Efficiency	η_d	W/A	0.6	0.72	-
Threshold Current	I _{th}	mA	-	30	40
Laser Series Resistance	R _S	Ω	-	2.0	2.5
Laser Forward Voltage	V _F	V	-	2.0	2.5
Thermistor Resistance @ 25°C, 1/ 2/	R _T	K Ω	-	10	-
Photodiode Dark Current, V _R =10V, LD I _F =0, 1/ 2/	I _D	nA	-	-	50
Laser Line Width	$\Delta\nu$	MHz	-	8	10
Beam Divergence @ FWHM	$\theta_{ } \times \theta_{\perp}$	°	-	6 X 32	8 X 34
Side Mode Suppression Ratio	SMSR	dB	-30	-	-
Polarization Extinction Ratio, 1/	PER	dB	-16	-19	-
Laser Polarization				TE	
Mode Structure			Fundamental Mode		

1/ Butterfly package 2/ TO-8 package

Handling Precautions

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.

How To Order

Part number example: PH920DBR080CM. Assign optical power from those available shown below. Use a three-digit format for all power entries. Call factory for special frequency selection and certification to certain atomic absorption lines. Butterfly package is offered at 50% of output powers shown.

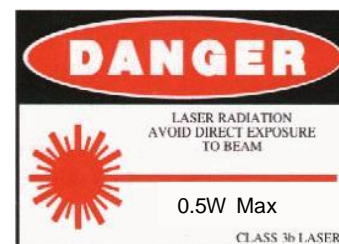
PH920DBR 

Operating Power (mW)

040
080
120

Package Type

CS Chip on Submount
CM 'C' Mount
BF Butterfly
T8 TO-8



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